# **One Watt Amplifier Transistor NPN Silicon**

# **MPS6717**

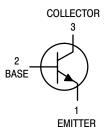
#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V <sub>CEO</sub>	80	Vdc
Collector–Base Voltage	V <sub>CBO</sub>	80	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	Vdc
Collector Current — Continuous	I <sub>C</sub>	500	mAdc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.0 8.0	Watts mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	2.5 20	Watts mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C



# THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit	
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	125	°C/W	
Thermal Resistance, Junction to Case	$R_{\theta JC}$	50	°C/W	



# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage <sup>(1)</sup> (I <sub>C</sub> = 1.0 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	80	_	Vdc	
Collector–Base Breakdown Voltage ( $I_C = 100 \mu Adc$ , $I_E = 0$ )	V <sub>(BR)CBO</sub>	80	_	Vdc	
Emitter–Base Breakdown Voltage ( $I_E = 10 \mu Adc, I_C = 0$ )	V <sub>(BR)EBO</sub>	5.0	_	Vdc	
ollector Cutoff Current $(V_{CB} = 60 \text{ Vdc}, I_E = 0)$		_	0.1	μAdc	
Emitter Cutoff Current $(V_{EB} = 5.0 \text{ Vdc}, I_C = 0)$	I <sub>EBO</sub>	_	10	μAdc	

<sup>1.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s; Duty Cycle  $\leq$  2.0%.

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$  unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS				
DC Current Gain ( $I_C = 50 \text{ mAdc}$ , $V_{CE} = 1.0 \text{ Vdc}$ ) ( $I_C = 250 \text{ mAdc}$ , $V_{CE} = 1.0 \text{ Vdc}$ )	h <sub>FE</sub>	80 50	 250	_
Collector–Emitter Saturation Voltage $(I_C = 250 \text{ mAdc}, I_B = 10 \text{ mAdc})$	V <sub>CE(sat)</sub>	_	0.5	Vdc
Base–Emitter On Voltage (I <sub>C</sub> = 250 mAdc, V <sub>CE</sub> = 1.0 Vdc)	V <sub>BE(on)</sub>	_	1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS	•		•	•
Collector–Base Capacitance (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>cb</sub>	_	30	pF
Small–Signal Current Gain (I <sub>C</sub> = 200 mAdc, V <sub>CE</sub> = 5.0 Vdc, f = 20 MHz)	h <sub>fe</sub>	2.5	25	_

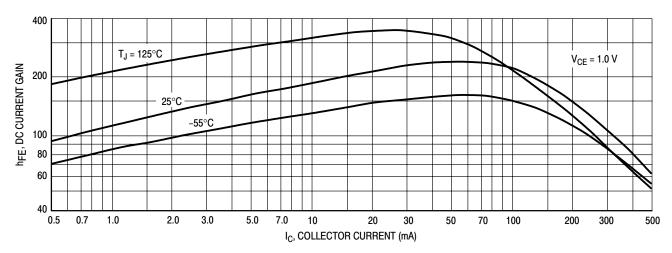


Figure 1. DC Current Gain

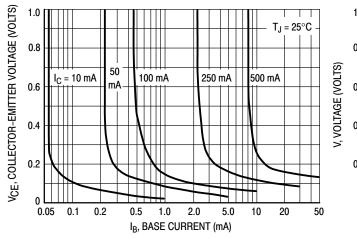


Figure 2. Collector Saturation Region

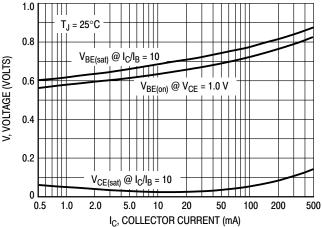


Figure 3. "On" Voltages

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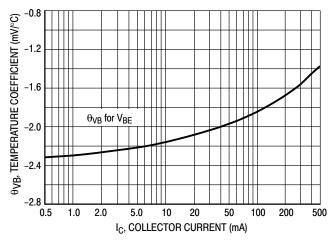


Figure 4. Base–Emitter Temperature Coefficient

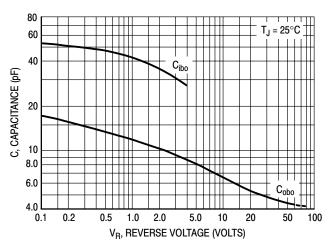


Figure 5. Capacitance

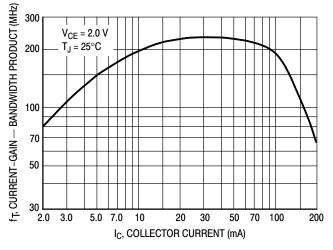


Figure 6. Current-Gain — Bandwidth Product

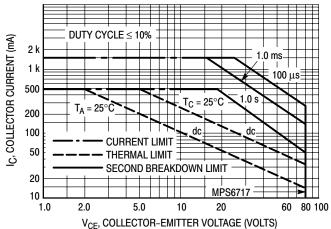
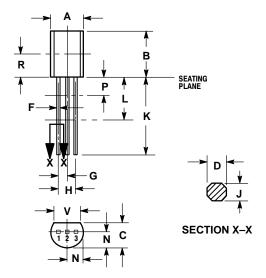


Figure 7. Active Region — Safe Operating Area

#### **MPS6717**

#### PACKAGE DIMENSIONS

CASE 029-05 (TO-226AE) ISSUE AD



NOTES:

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   MIMIMUM. LEAD DIMENSION IS UNCONTROLLED.
   IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.022	0.46	0.56
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.135		3.43	
٧	0.135		3.43	

STYLE 1:

PIN 1. EMITTER

2. BASE

3. COLLECTOR

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